

EC3225HSET-10.000M



ELECTRICAL SPECIFICATIONS

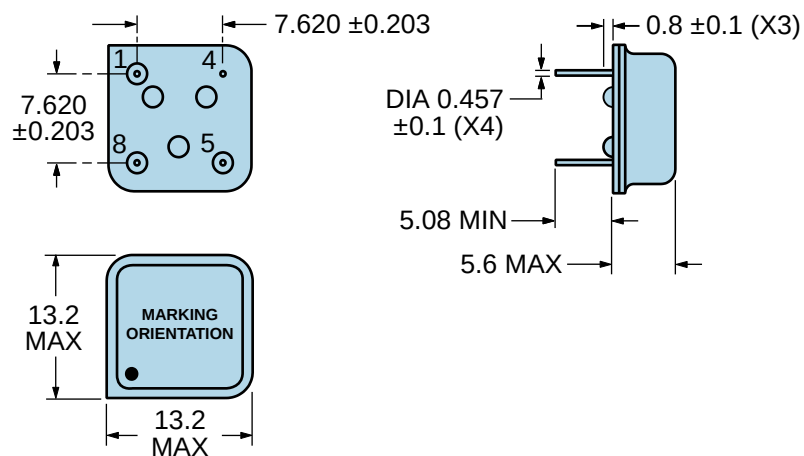
Nominal Frequency	10.000MHz
Frequency Tolerance/Stability	±25ppm Maximum (Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, Output Load Change, First Year Aging at 25°C, Shock, and Vibration)
Aging at 25°C	±5ppm/year Maximum
Operating Temperature Range	-40°C to +85°C
Supply Voltage	3.3Vdc ±10%
Input Current	10mA Maximum
Output Voltage Logic High (Voh)	2.4Vdc Minimum with TTL Load, 2.7Vdc Minimum with LVCMOS Load
Output Voltage Logic Low (Vol)	0.4Vdc Maximum with TTL Load or with LVCMOS Load
Rise/Fall Time	5nSec Maximum (Measured at 0.4Vdc to 2.4Vdc w/TTL Load, 20% to 80% of waveform w/LVCMOS Load)
Duty Cycle	50 ±10(%) (Measured at 50% of waveform w/LVCMOS Load)
Load Drive Capability	2TTL Load or 15pF LVCMOS Load Maximum
Output Logic Type	CMOS
Control Voltage	1.65Vdc ±1.65Vdc
Frequency Deviation	±50ppm Minimum
Linearity	±20% Maximum
Transfer Function	Positive Transfer Characteristic
Absolute Clock Jitter	±100pSec Maximum
One Sigma Clock Period Jitter	±25pSec Maximum
Start Up Time	10mSec Maximum
Storage Temperature Range	-55°C to +125°C

ENVIRONMENTAL & MECHANICAL SPECIFICATIONS

Fine Leak Test	MIL-STD-883, Method 1014, Condition A
Gross Leak Test	MIL-STD-883, Method 1014, Condition C
Lead Integrity	MIL-STD-883, Method 2004
Mechanical Shock	MIL-STD-202, Method 213, Condition C
Resistance to Soldering Heat	MIL-STD-202, Method 210
Resistance to Solvents	MIL-STD-202, Method 215
Solderability	MIL-STD-883, Method 2003
Temperature Cycling	MIL-STD-883, Method 1010
Vibration	MIL-STD-883, Method 2007, Condition A

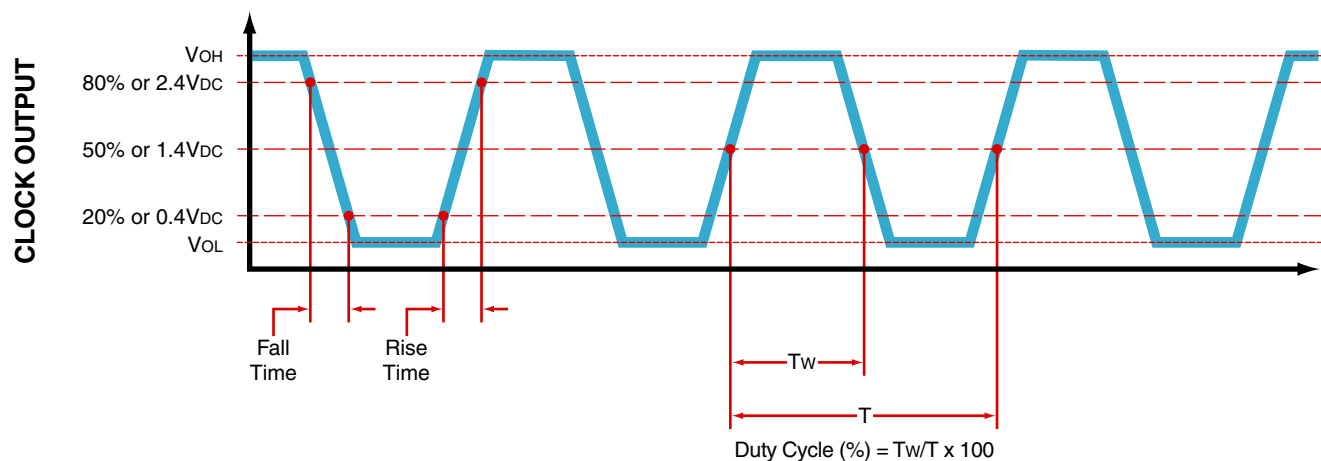
EC3225HSET-10.000M

MECHANICAL DIMENSIONS (all dimensions in millimeters)



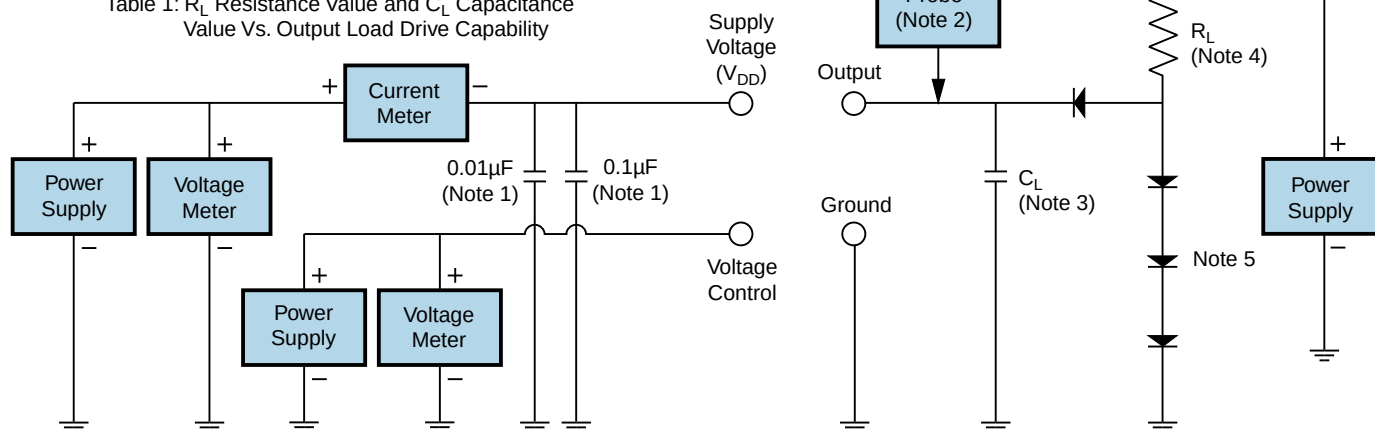
PIN	CONNECTION
1	Control Voltage
4	Ground/Case Ground
5	Output
8	Supply Voltage

LINE	MARKING
1	ECLIPTEK
2	EC32 <i>EC32=Product Series</i>
3	10.000M
4	XXYYZZ <i>XX=Ecliptek Manufacturing Code</i> <i>Y=Last Digit of the Year</i> <i>ZZ=Week of the Year</i>

EC3225HSET-10.000M **OUTPUT WAVEFORM**

Output Load Drive Capability	R _L Value (Ohms)	C _L Value (pF)
10TTL	390	15
5TTL	780	15
2TTL	1100	6
10LSTTL	2000	15
1TTL	2200	3

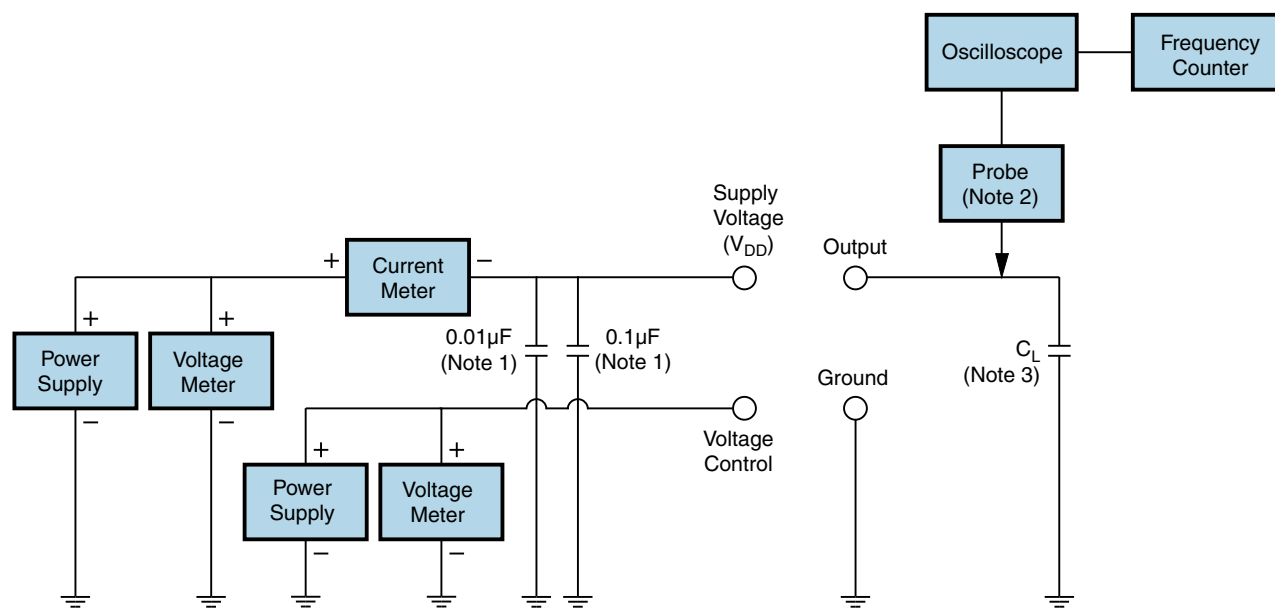
Table 1: R_L Resistance Value and C_L Capacitance Value Vs. Output Load Drive Capability



Note 5: All diodes are MMBD7000, MMBD914, or equivalent.

EC3225HSET-10.000M

Test Circuit for CMOS Output



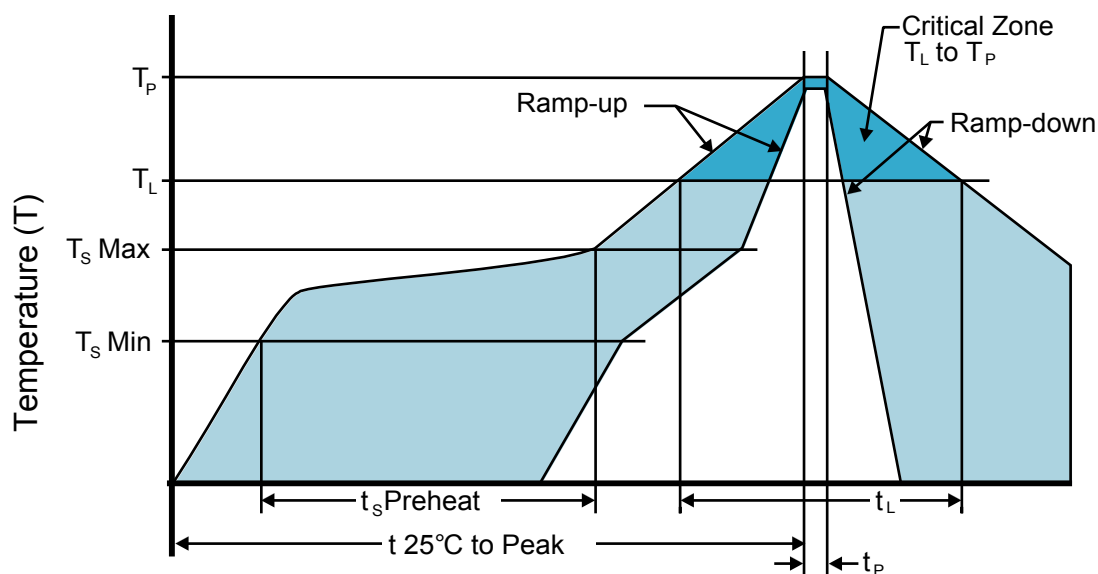
Note 1: An external $0.01\mu\text{F}$ ceramic bypass capacitor in parallel with a $0.1\mu\text{F}$ high frequency ceramic bypass capacitor close (less than 2mm) to the package ground and supply voltage pin is required.

Note 2: A low capacitance ($<12\text{pF}$), 10X attenuation factor, high impedance ($>10\text{Mohms}$), and high bandwidth ($>300\text{MHz}$) passive probe is recommended.

Note 3: Capacitance value C_L includes sum of all probe and fixture capacitance.

EC3225HSET-10.000M

Recommended Solder Reflow Methods



High Temperature Solder Bath (Wave Solder) Time (t)

Ts MAX to Tl (Ramp-up Rate) 3°C/Second Maximum

Preheat

- Temperature Minimum (Ts MIN) 150°C
- Temperature Typical (Ts TYP) 175°C
- Temperature Maximum (Ts MAX) 200°C
- Time (ts MIN) 60 - 180 Seconds

Ramp-up Rate (Tl to Tp) 3°C/Second Maximum

Time Maintained Above:

- Temperature (Tl) 217°C
- Time (tL) 60 - 150 Seconds

Peak Temperature (Tp) 260°C Maximum for 10 Seconds Maximum

Target Peak Temperature (Tp Target) 250°C +0/-5°C

Time within 5°C of actual peak (tp) 20 - 40 Seconds

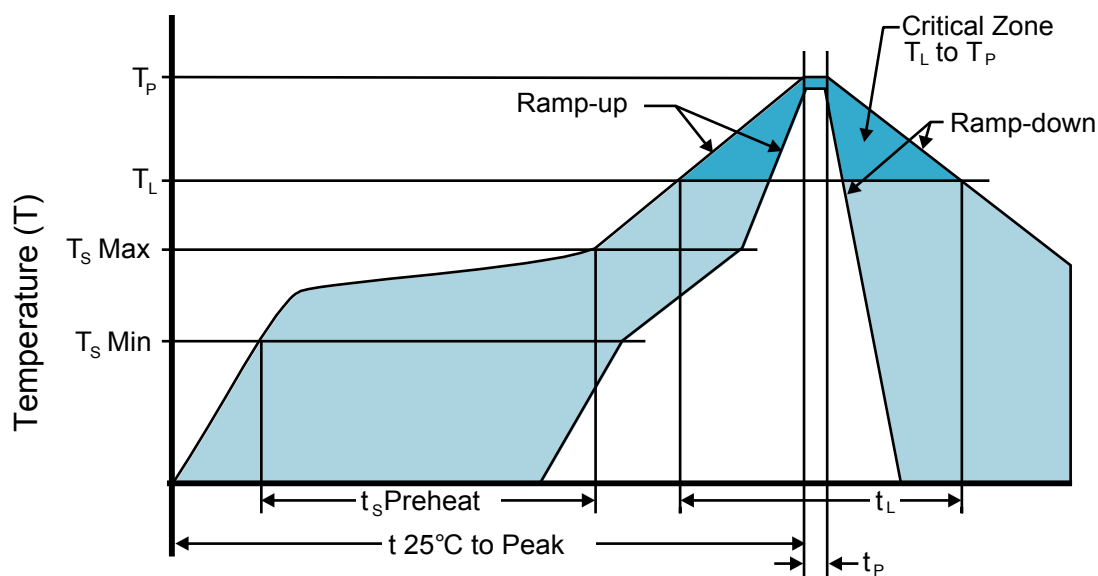
Ramp-down Rate 6°C/Second Maximum

Time 25°C to Peak Temperature (t) 8 Minutes Maximum

Moisture Sensitivity Level Level 1

EC3225HSET-10.000M

Recommended Solder Reflow Methods



Low Temperature Infrared/Convection 185°C

Ts MAX to Tl (Ramp-up Rate) 5°C/Second Maximum

Preheat

- Temperature Minimum (Ts MIN) N/A
- Temperature Typical (Ts TYP) 150°C
- Temperature Maximum (Ts MAX) N/A
- Time (ts MIN) 60 - 120 Seconds

Ramp-up Rate (Tl to Tp) 5°C/Second Maximum

Time Maintained Above:

- Temperature (Tl) 150°C
- Time (tL) 200 Seconds Maximum

Peak Temperature (Tp) 185°C Maximum

Target Peak Temperature (Tp Target) 185°C Maximum 2 Times

Time within 5°C of actual peak (tp) 10 Seconds Maximum 2 Times

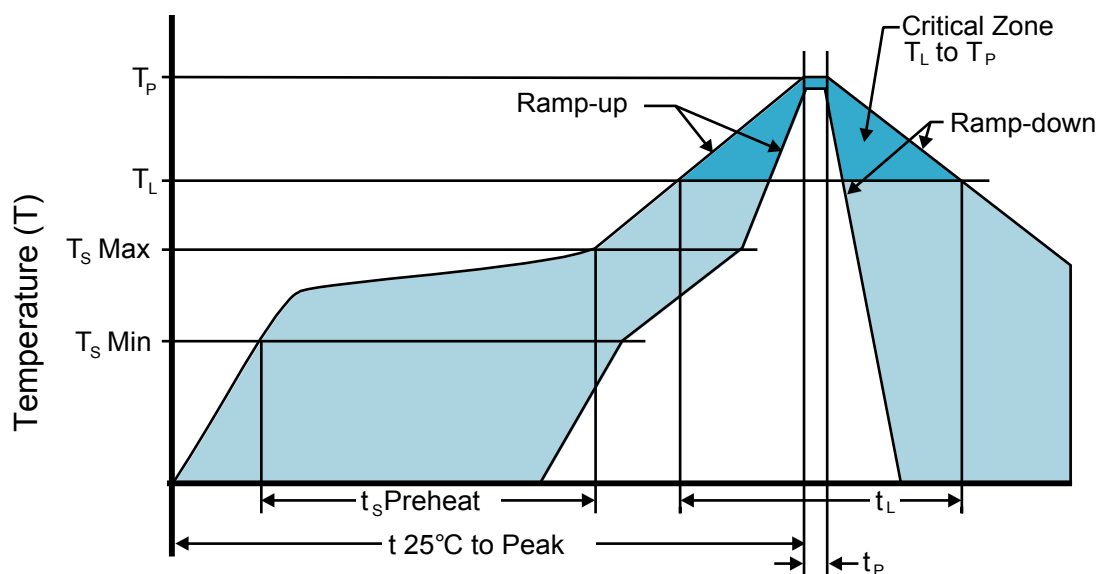
Ramp-down Rate 5°C/Second Maximum

Time 25°C to Peak Temperature (t) N/A

Moisture Sensitivity Level Level 1

EC3225HSET-10.000M

Recommended Solder Reflow Methods



Low Temperature Solder Bath (Wave Solder) Time (t)

Ts MAX to Tl (Ramp-up Rate) 5°C/Second Maximum

Preheat

- Temperature Minimum (Ts MIN) N/A
- Temperature Typical (Ts TYP) 150°C
- Temperature Maximum (Ts MAX) N/A
- Time (ts MIN) 30 - 60 Seconds

Ramp-up Rate (Tl to Tp) 5°C/Second Maximum

Time Maintained Above:

- Temperature (Tl) 150°C
- Time (tL) 200 Seconds Maximum

Peak Temperature (Tp) 245°C Maximum

Target Peak Temperature (Tp Target) 245°C Maximum 1 Time / 235°C Maximum 2 Times

Time within 5°C of actual peak (tp) 5 Seconds Maximum 1 Time / 15 Seconds Maximum 2 Times

Ramp-down Rate 5°C/Second Maximum

Time 25°C to Peak Temperature (t) N/A

Moisture Sensitivity Level Level 1

Low Temperature Manual Soldering

185°C Maximum for 10 Seconds Maximum, 2 times Maximum.

High Temperature Manual Soldering

260°C Maximum for 5 Seconds Maximum, 2 times Maximum.